Dual high-voltage switching diodes Rev. 07 — 19 March 2010

Product data sheet

#### 1. **Product profile**

### **1.1 General description**

Dual high-voltage switching diodes, encapsulated in small Surface-Mounted Device (SMD) plastic packages.

#### Table 1. **Product overview**

Type number	Package		Configuration
	NXP	JEDEC	
BAV23A	SOT23	TO-236AB	dual common anode
BAV23C	SOT23	TO-236AB	dual common cathode
BAV23S	SOT23	TO-236AB	dual series
BAV23	SOT143B	-	dual isolated

### **1.2 Features and benefits**

- High switching speed:  $t_{rr} \le 50$  ns
- Low leakage current
- Repetitive peak reverse voltage:  $V_{RRM} \leq 250 \ V$
- Low capacitance:  $C_d \le 2 pF$
- Small SMD plastic package

### **1.3 Applications**

- High-speed switching at high voltage
- High-voltage general-purpose switching

### 1.4 Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
I <sub>R</sub>	reverse current	V <sub>R</sub> = 200 V	-	-	100	nA
V <sub>R</sub>	reverse voltage		-	-	200	V
t <sub>rr</sub>	reverse recovery time		<u>[1]</u> _	-	50	ns

[1] When switched from  $I_F = 10$  mA to  $I_R = 10$  mA;  $R_L = 100 \Omega$ ; measured at  $I_R = 1$  mA.



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## 2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
BAV23A			
1	cathode (diode 1)		
2	cathode (diode 2)		3
3	common anode	1 2	
BAV23C			
1	anode (diode 1)	·	_
2	anode (diode 2)		3
3	common cathode	1 2	1 2 006aab03
BAV23S			
1	anode (diode 1)		
2	cathode (diode 2)		3
3	cathode (diode 1), anode (diode 2)	1 2	
BAV23			
1	cathode (diode 1)		
2	cathode (diode 2)		4 3
3	anode (diode 2)		
4	anode (diode 1)		1 2 006aab100

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### 3. Ordering information

Table 4. Orde	ering inform	nation	
Type number	Package		
	Name	Description	Version
BAV23A	-	plastic surface-mounted package; 3 leads	SOT23
BAV23C			
BAV23S			
BAV23	-	plastic surface-mounted package; 4 leads	SOT143B

### 4. Marking

Table 5.Marking codes	
Type number	Marking code <sup>[1]</sup>
BAV23A	*V0
BAV23C	*V9
BAV23S	*V5
BAV23	*L3

[1] \* = -: made in Hong Kong

\* = p: made in Hong Kong

\* = t: made in Malaysia

\* = W: made in China

### 5. Limiting values

#### Table 6.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

		•••	,		
Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V <sub>RRM</sub>	repetitive peak reverse voltage		-	250	V
V <sub>R</sub>	reverse voltage		-	200	V
l <sub>F</sub>	forward current		<u>[1]</u> _	225	mA
			[2] _	125	mA
I <sub>FRM</sub>	repetitive peak forward current		-	625	mA
I <sub>FSM</sub>	non-repetitive peak forward current	square wave	[3]		
		$t_p = 1 \ \mu s$	-	9	А
		t <sub>p</sub> = 100 μs	-	3	А
		t <sub>p</sub> = 10 ms	-	1.7	А

#### Dual high-voltage switching diodes

Table 6.	Limiting	values	continued
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In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per device					
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	[4] _	250	mW
T <sub>j</sub>	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

- [1] Single diode loaded.
- [2] Double diode loaded.
- [3]  $T_i = 25 \circ C$  prior to surge.
- [4] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

### 6. Thermal characteristics

Table 7.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per devic	ce					
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	<u>[1]</u> _	-	500	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		-	-	360	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

### 7. Characteristics

#### Table 8.Characteristics

 $T_{amb} = 25 \ ^{\circ}C$  unless otherwise specified.

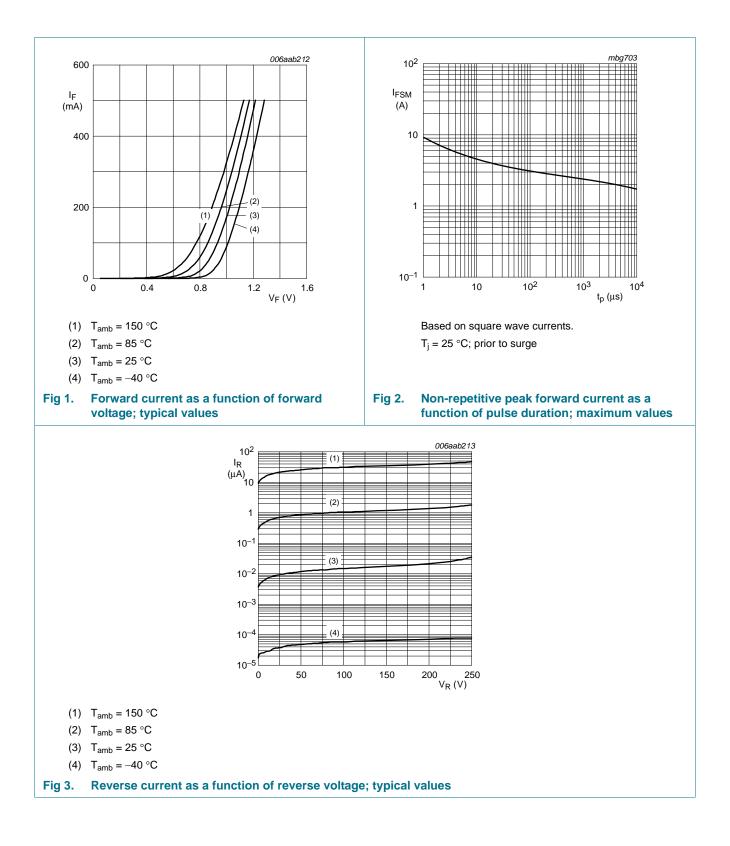
· anno =•						
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode	)					
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 100 mA	-	-	1.0	V
		I <sub>F</sub> = 200 mA	-	-	1.25	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 200 V	-	-	100	nA
		$V_R = 200 \text{ V}; \text{ T}_j = 150 ^{\circ}\text{C}$	-	-	100	μΑ
C <sub>d</sub>	diode capacitance	$f = 1 MHz; V_R = 0 V$	-	-	2	pF
t <sub>rr</sub>	reverse recovery time		<u>[1]</u> _	-	50	ns

[1] When switched from I<sub>F</sub> = 10 mA to I<sub>R</sub> = 10 mA; R<sub>L</sub> = 100  $\Omega$ ; measured at I<sub>R</sub> = 1 mA.

### **NXP Semiconductors**

## **BAV23 series**

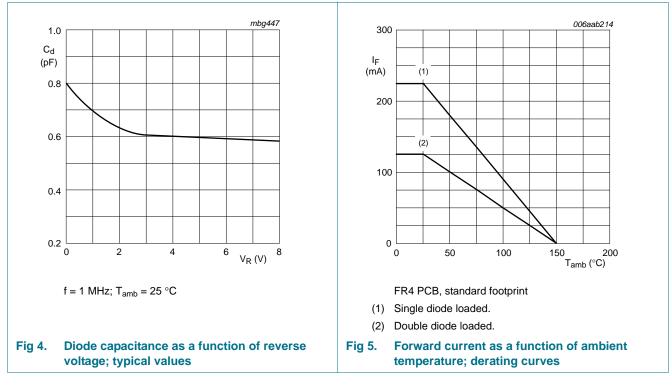
#### Dual high-voltage switching diodes



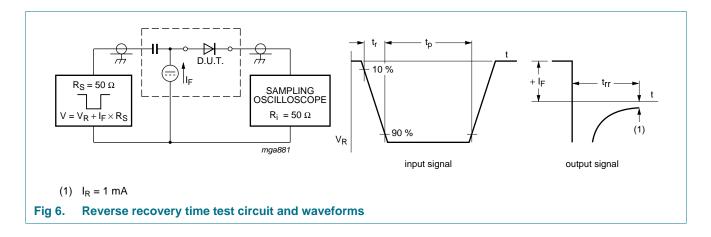
### **NXP Semiconductors**

## **BAV23 series**

#### Dual high-voltage switching diodes

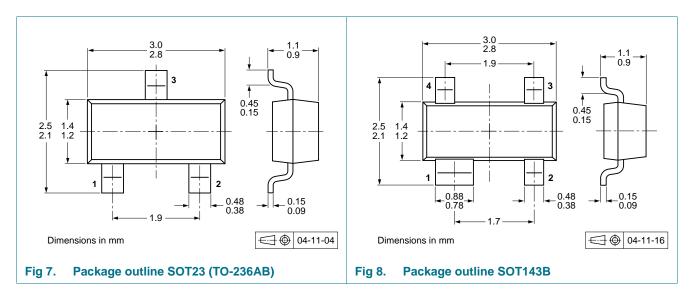


### 8. Test information



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### 9. Package outline



### **10. Packing information**

#### Table 9.Packing methods

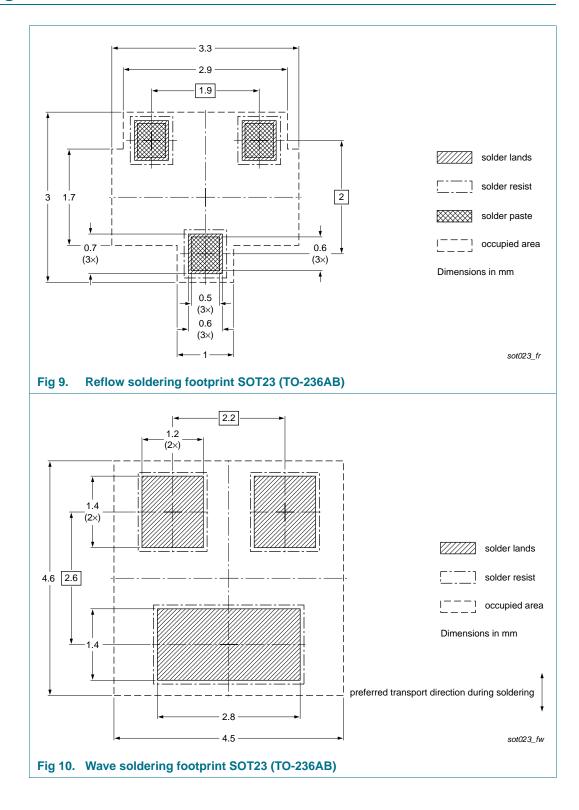
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing	quantity
			3000	10000
BAV23A	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235
BAV23C				
BAV23S				
BAV23	SOT143B	4 mm pitch, 8 mm tape and reel	-215	-235

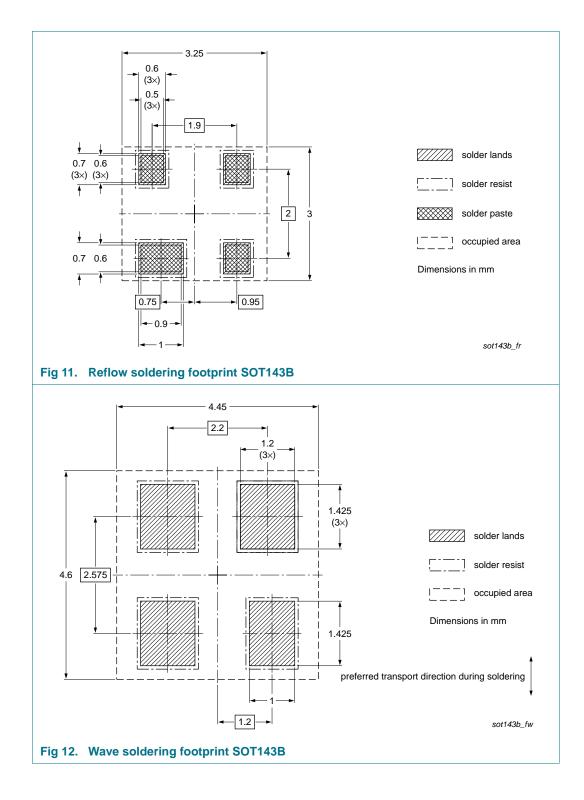
[1] For further information and the availability of packing methods, see Section 14.

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### **11. Soldering**



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## 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BAV23_SER_7	20100319	Product data sheet	-	BAV23_SER_6	
Modifications:	<ul> <li>Type numb</li> </ul>	ers BAV23A/DG, BAV23C/D	G, BAV23S/DG and BA	V23/DG deleted	
	<ul> <li>Type numb</li> </ul>	ers BAV23A and BAV23C ac	lded		
	<ul> <li><u>Table 5 "Marking codes"</u>: updated</li> </ul>				
	<ul> <li>Figure 6: adaptation of test condition to specified characteristics in Table 8</li> </ul>				
	<ul> <li>Figure 9, 10, 11 and 12: updated</li> </ul>				
	Section 13	"Legal information": updated			
BAV23_SER_6	20080303	Product data sheet	-	BAV23S_5	
				BAV23_2	
BAV23S_5	20011012	Product specification	-	BAV23S_4	
BAV23 2	19960917	Product specification		BAV23 1	

### 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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BAV23\_SER\_7
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